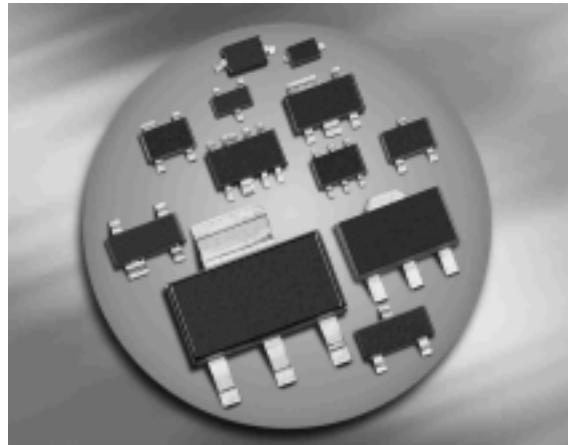
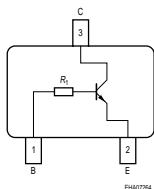
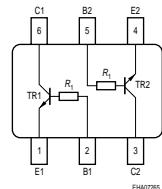


### NPN silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in resistor ( $R_1=4.7\text{ k}\Omega$ )
- BCR119S: Two internally isolated transistors with good matching in one multichip package
- BCR119S: For orientation in reel see package information below
- Pb-free (RoHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101


**BCR119/F/W**

**BCR119S**


| Type    | Marking | Pin Configuration |      |      |      |      |      | Package |
|---------|---------|-------------------|------|------|------|------|------|---------|
| BCR119  | WKs     | 1=B               | 2=E  | 3=C  | -    | -    | -    | SOT23   |
| BCR119F | WKs     | 1=B               | 2=E  | 3=C  | -    | -    | -    | TSFP-3  |
| BCR119S | WKs     | 1=E1              | 2=B1 | 3=C2 | 4=E2 | 5=B2 | 6=C1 | SOT363  |
| BCR119W | WKs     | 1=B               | 2=E  | 3=C  | -    | -    | -    | SOT323  |

<sup>1)</sup>Pb-containing package may be available upon special request

**Maximum Ratings**

| Parameter   | Symbol     | Value                    | Unit             |
|---|------------|--------------------------|------------------|
| Collector-emitter voltage   | $V_{CEO}$  | 50                       | V                |
| Collector-base voltage  | $V_{CBO}$  | 50                       |                  |
| Input forward voltage   | $V_i(fwd)$ | 30                       |                  |
| Input reverse voltage   | $V_i(rev)$ | 5                        |                  |
| DC collector current  | $I_E$      | 100                      | mA               |
| Total power dissipation-<br>BCR119, $T_S \leq 102^\circ\text{C}$<br>BCR119F, $T_S \leq 128^\circ\text{C}$<br>BCR119S, $T_S \leq 115^\circ\text{C}$<br>BCR119W, $T_S \leq 124^\circ\text{C}$ | $P_{tot}$  | 200<br>250<br>250<br>250 | mW               |
| Junction temperature  | $T_j$      | 150                      | $^\circ\text{C}$ |
| Storage temperature   | $T_{stg}$  | -65 ... 150              |                  |

**Thermal Resistance**

| Parameter   | Symbol     | Value   | Unit |
|---|------------|---|------|
| Junction - soldering point <sup>1)</sup><br>BCR119<br>BCR119F<br>BCR119S<br>BCR119W | $R_{thJS}$ | $\leq 240$<br>$\leq 90$<br>$\leq 140$<br>$\leq 105$ | K/W  |

<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

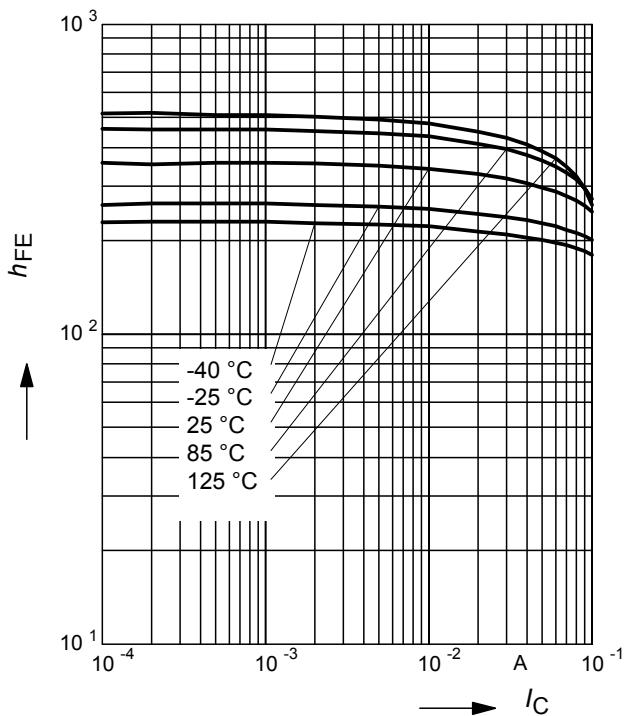
| Parameter   | Symbol                      | Values |      |      | Unit       |
|---|-----------------------------|--------|------|------|------------|
|   |                             | min.   | typ. | max. |            |
| <b>DC Characteristics</b>   |                             |        |      |      |            |
| Collector-emitter breakdown voltage<br>$I_C = 100 \mu\text{A}, I_B = 0$                           | $V_{(\text{BR})\text{CEO}}$ | 50     | -    | -    | V          |
| Collector-base breakdown voltage<br>$I_C = 10 \mu\text{A}, I_E = 0$                               | $V_{(\text{BR})\text{CBO}}$ | 50     | -    | -    |            |
| Collector-base cutoff current<br>$V_{CB} = 40 \text{ V}, I_E = 0$                                 | $I_{\text{CBO}}$            | -      | -    | 100  | nA         |
| Emitter-base cutoff current<br>$V_{EB} = 5 \text{ V}, I_C = 0$                                    | $I_{\text{EBO}}$            | -      | -    | 100  | nA         |
| DC current gain <sup>1)</sup><br>$I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$                       | $h_{\text{FE}}$             | 120    | -    | 630  | -          |
| Collector-emitter saturation voltage <sup>1)</sup><br>$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | $V_{\text{CEsat}}$          | -      | -    | 0.3  | V          |
| Input off voltage<br>$I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$                                | $V_{i(\text{off})}$         | 0.4    | -    | 0.8  |            |
| Input on voltage<br>$I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$                                  | $V_{i(\text{on})}$          | 0.5    | -    | 1.1  |            |
| Input resistor  | $R_1$                       | 3.2    | 4.7  | 6.2  | k $\Omega$ |

**AC Characteristics**

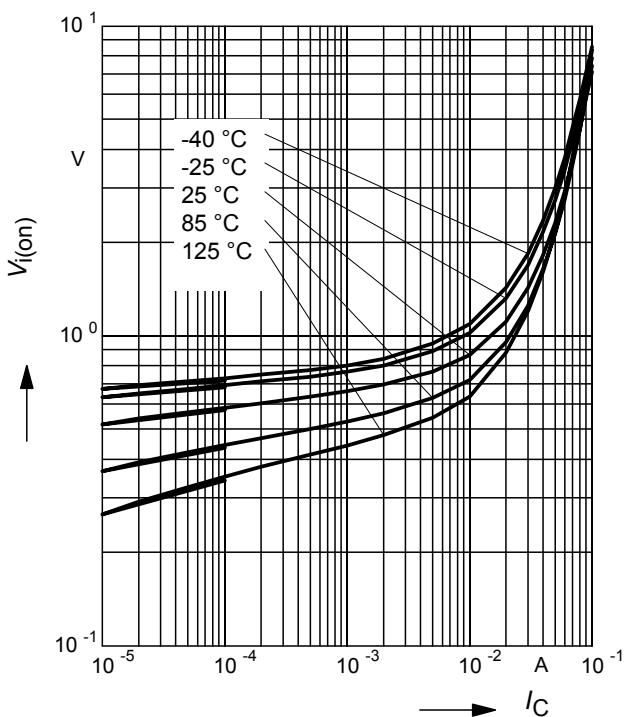
|  |          |   |     |   |     |
|--|----------|---|-----|---|-----|
| Transition frequency<br>$I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$ | $f_T$    | - | 150 | - | MHz |
| Collector-base capacitance<br>$V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$                 | $C_{cb}$ | - | 3   | - | pF  |

<sup>1</sup>Pulse test:  $t < 300\mu\text{s}$ ;  $D < 2\%$

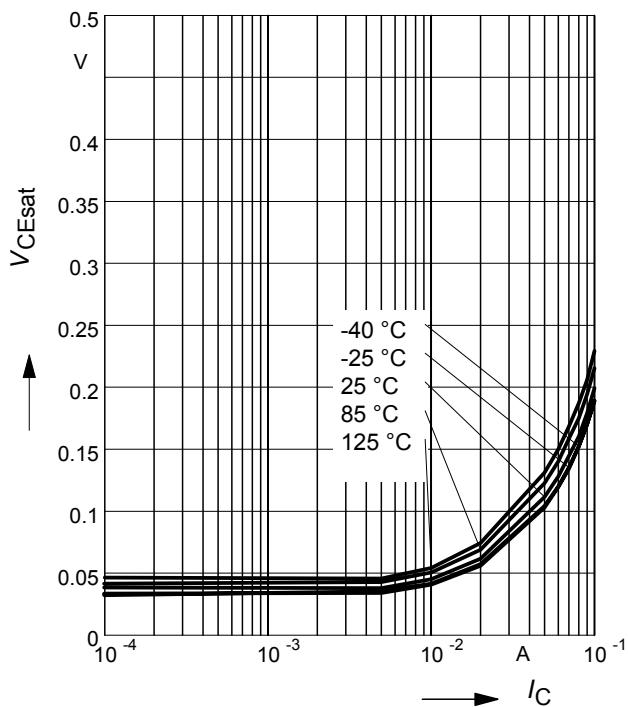
**DC current gain**  $h_{FE} = f(I_C)$   
 $V_{CE} = 5V$  (common emitter configuration)



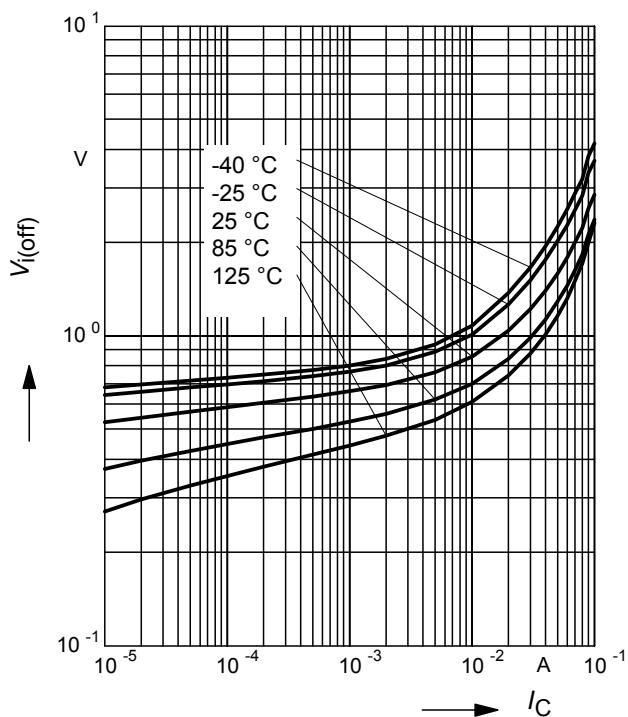
**Input on Voltage**  $V_{i(on)} = f(I_C)$   
 $V_{CE} = 0.3V$  (common emitter configuration)



**Collector-emitter saturation voltage**  
 $V_{CEsat} = f(I_C)$ ,  $I_C/I_B = 20$

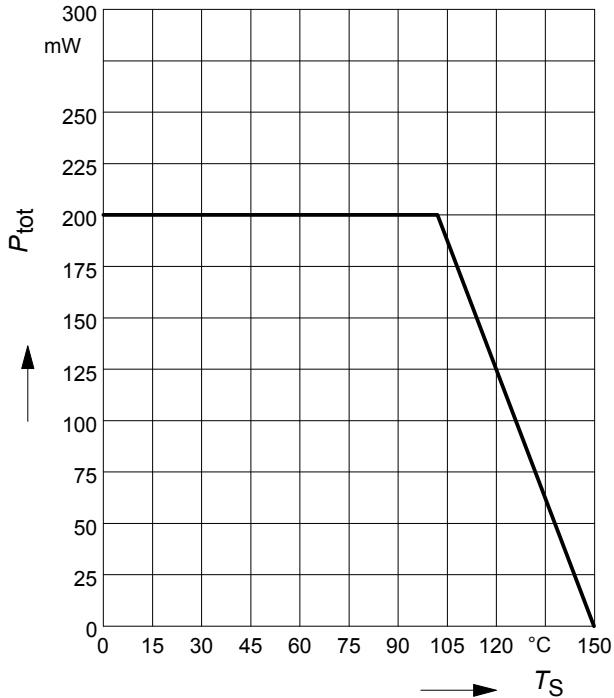


**Input off voltage**  $V_{i(off)} = f(I_C)$   
 $V_{CE} = 5V$  (common emitter configuration)



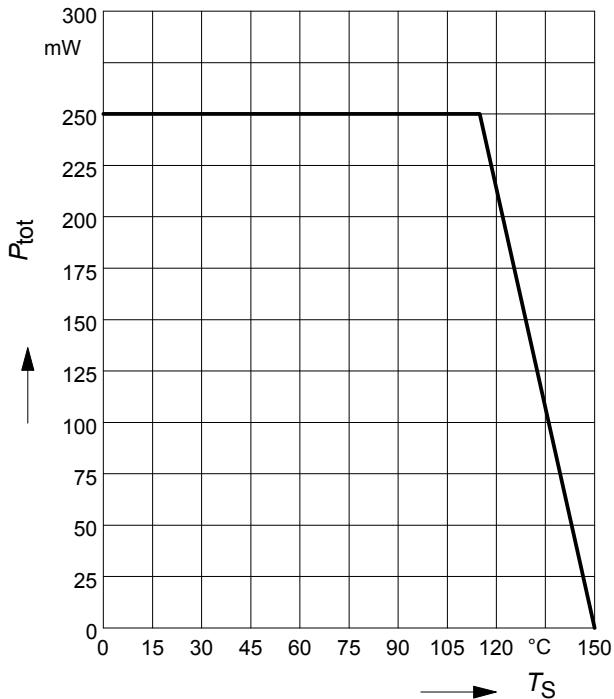
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

BCR119



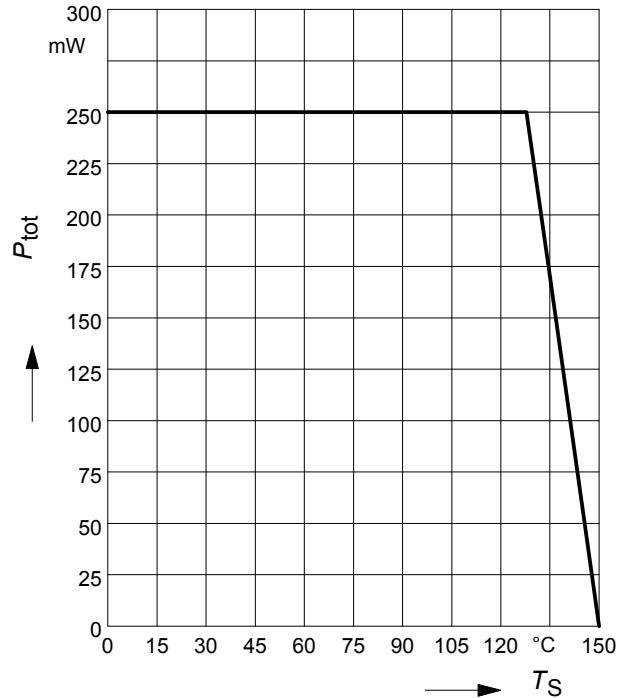
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

BCR119S



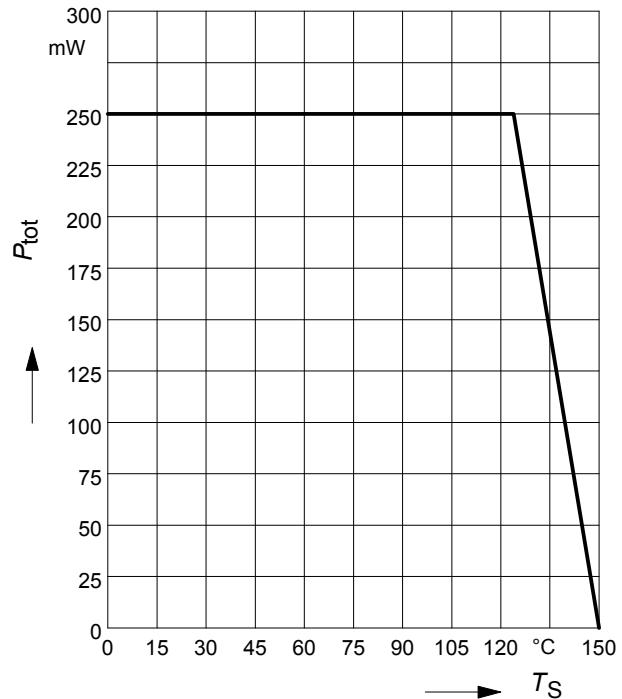
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

BCR119F



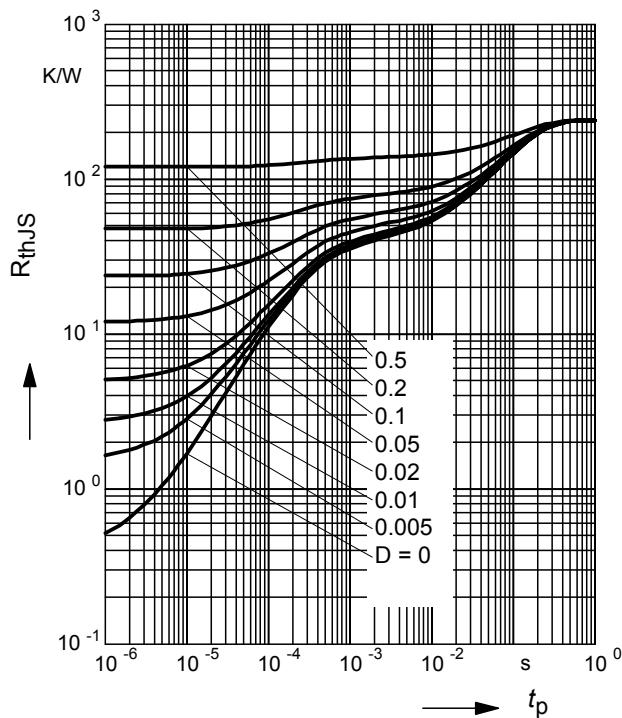
**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

BCR119W



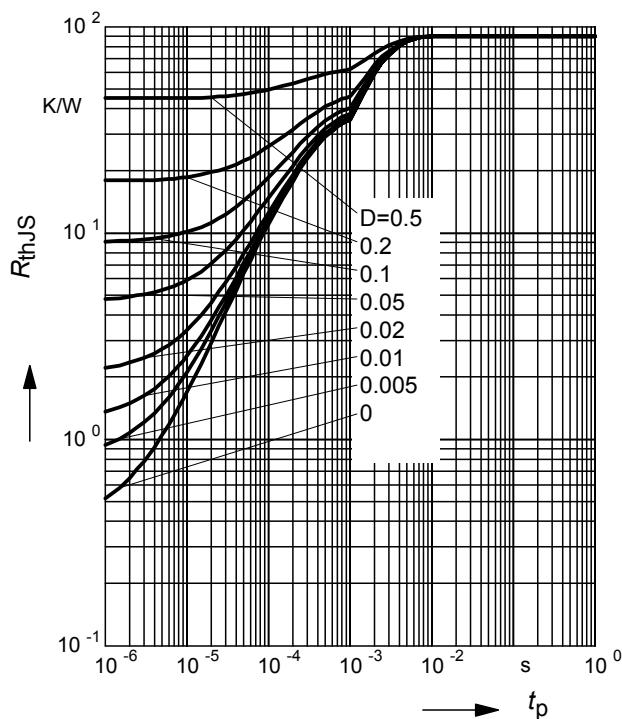
**Permissible Pulse Load  $R_{\text{thJS}} = f(t_p)$**

BCR119



**Permissible Pulse Load  $R_{\text{thJS}} = f(t_p)$**

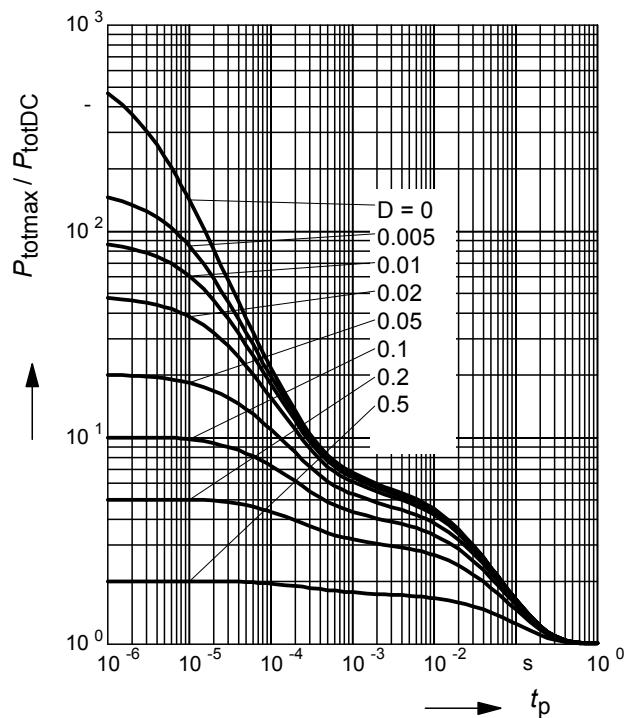
BCR119F



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

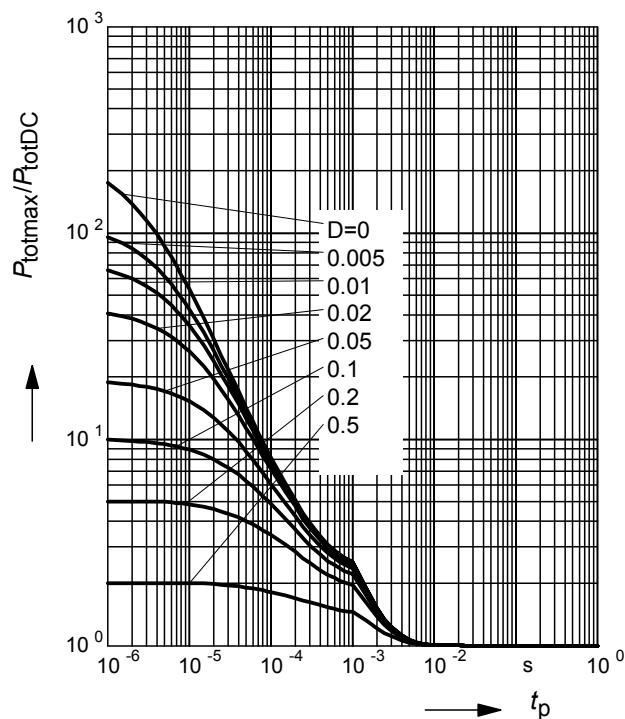
BCR119



**Permissible Pulse Load**

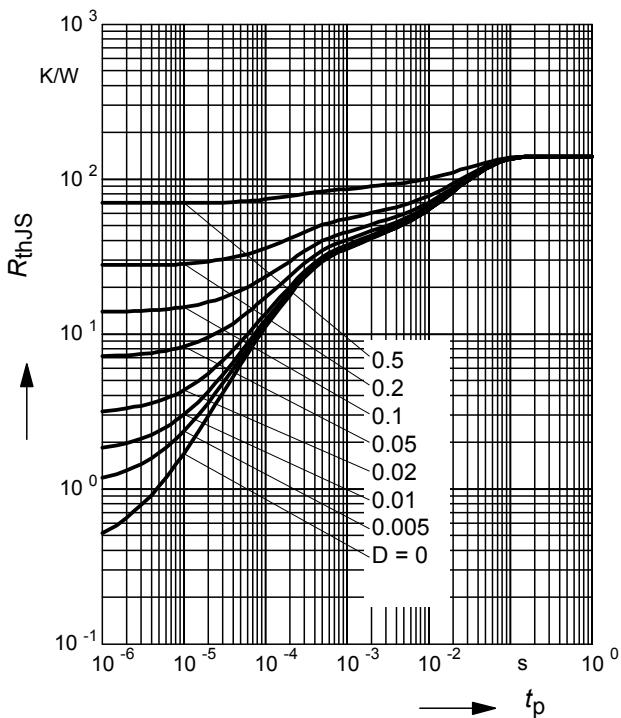
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR119F



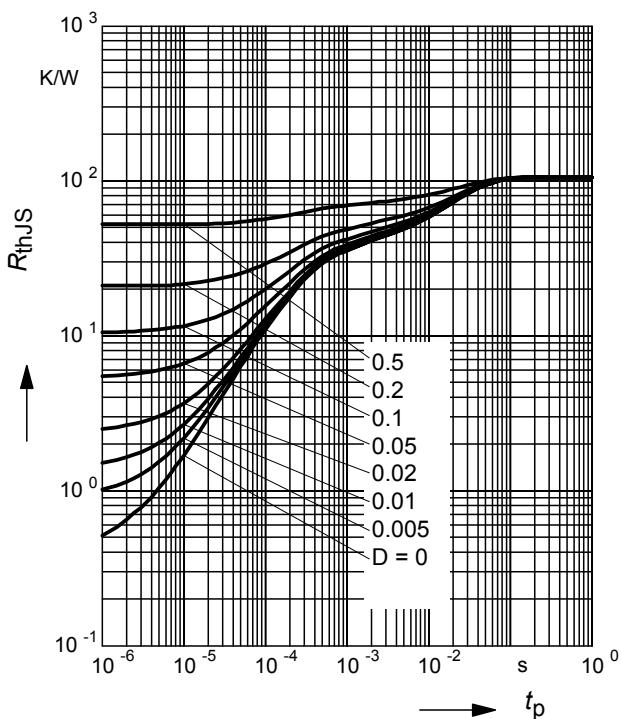
**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$**

BCR119S



**Permissible Puls Load  $R_{\text{thJS}} = f(t_p)$**

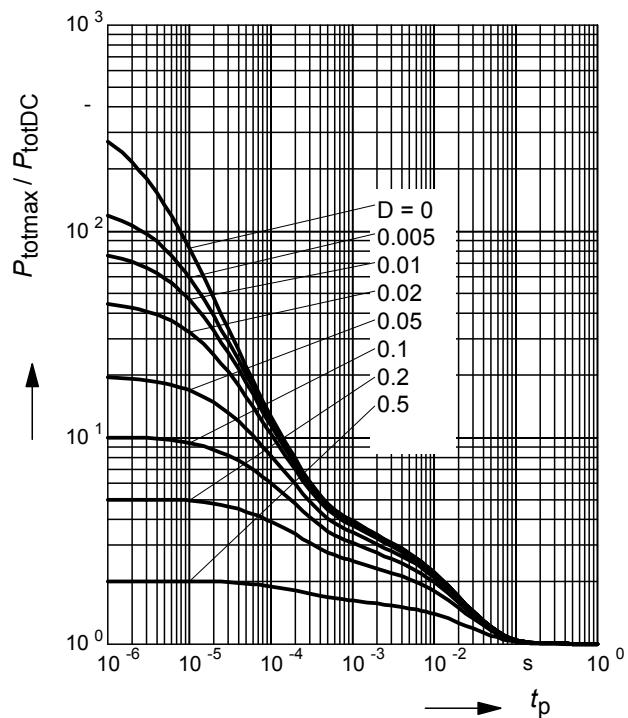
BCR119W



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

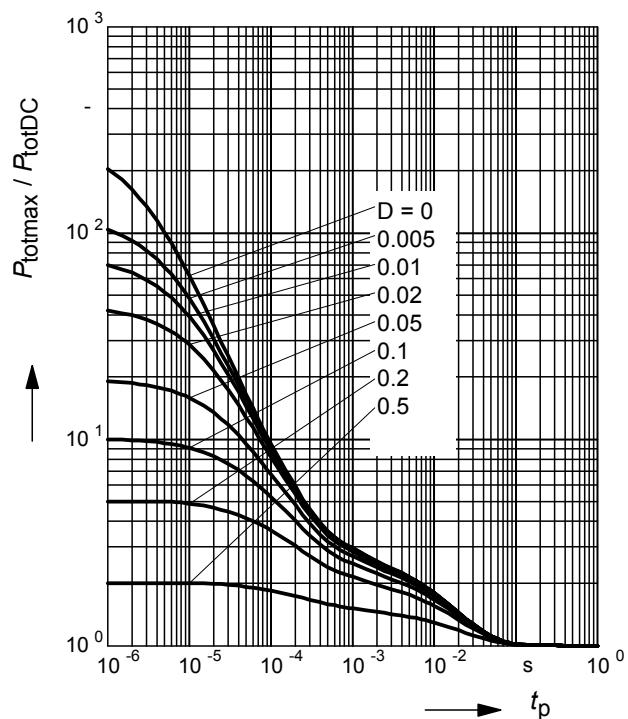
BCR119S



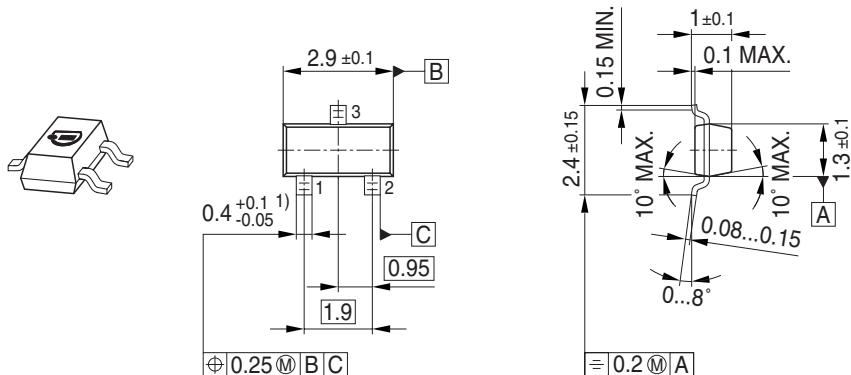
**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR119W

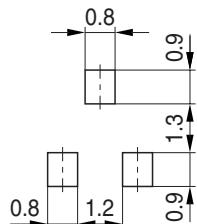


## Package Outline

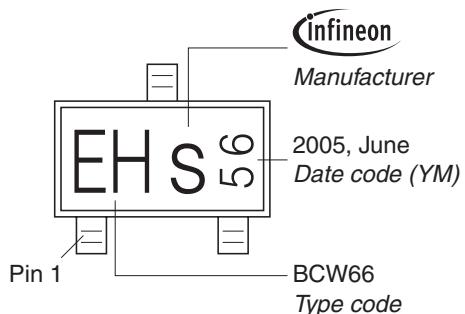


1) Lead width can be 0.6 max. in dambar area

## Foot Print

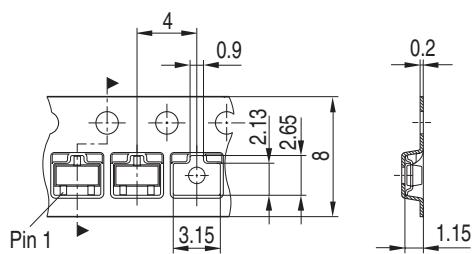


## Marking Layout (Example)

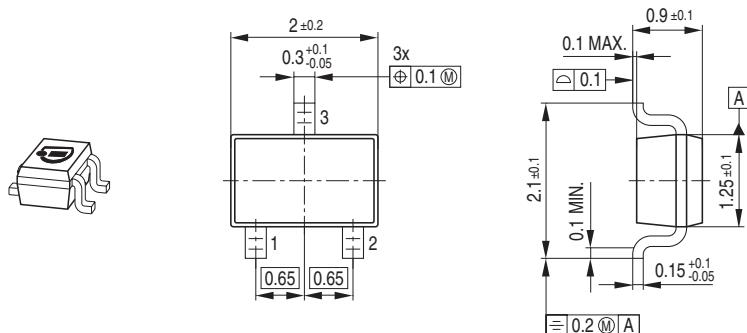


## Standard Packing

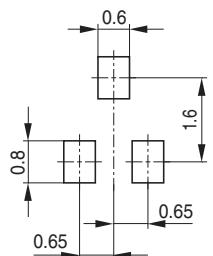
Reel ø180 mm = 3.000 Pieces/Reel  
Reel ø330 mm = 10.000 Pieces/Reel



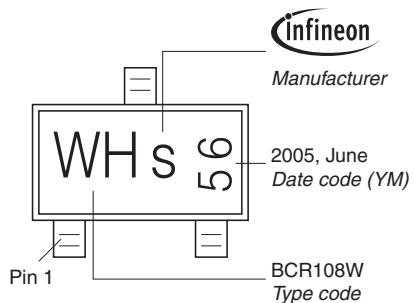
### Package Outline



### Foot Print

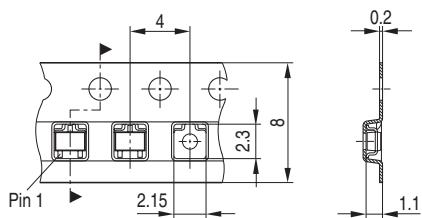


### Marking Layout (Example)

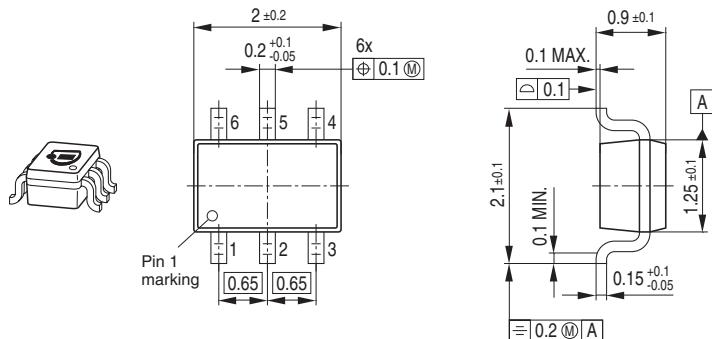


### Standard Packing

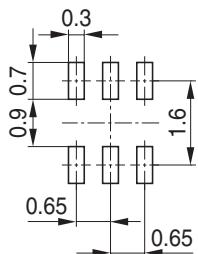
Reel ø180 mm = 3.000 Pieces/Reel  
Reel ø330 mm = 10.000 Pieces/Reel



### Package Outline

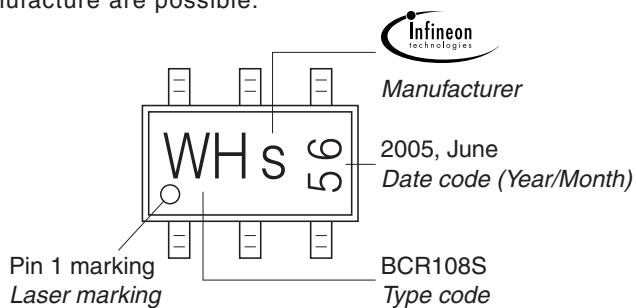


### Foot Print



### Marking Layout (Example)

Small variations in positioning of Date code, Type code and Manufacture are possible.

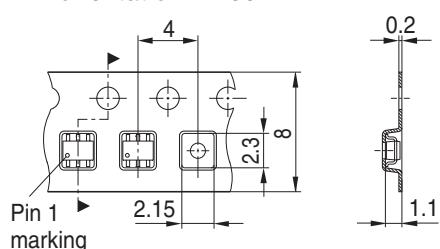


### Standard Packing

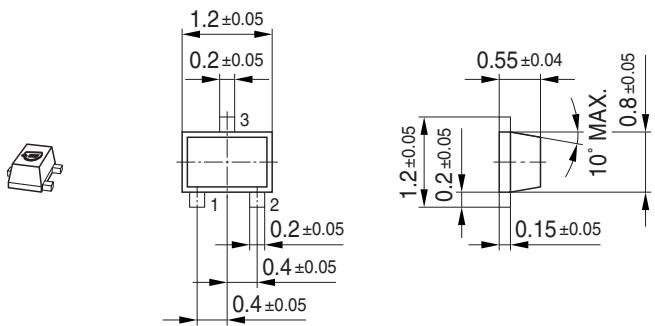
Reel ø180 mm = 3.000 Pieces/Reel

Reel ø330 mm = 10.000 Pieces/Reel

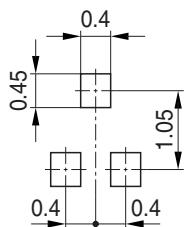
For symmetric types no defined Pin 1 orientation in reel.



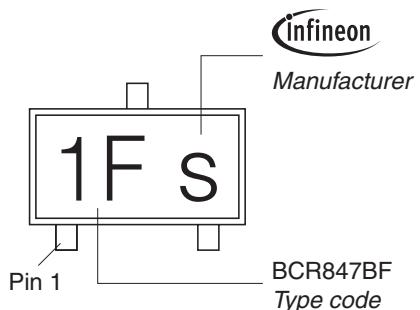
## Package Outline



## Foot Print

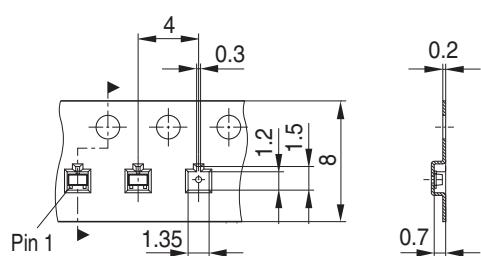


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
 Reel ø330 mm = 10.000 Pieces/Reel



---

Edition 2006-02-01

Published by

Infineon Technologies AG

81726 München, Germany

© Infineon Technologies AG 2007.

All Rights Reserved.

### **Attention please!**

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

### **Information**

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office ([www.infineon.com](http://www.infineon.com)).

### **Warnings**

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system.

Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.



**Стандарт  
Электрон  
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

**Наши контакты:**

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литер Н,  
помещение 100-Н Офис 331